

O.I.P.E.		PATENT DATE
SCANNED	NO. 2	Q.A.

APPLICATION NO. 09/901109	CONT/PRIOR	CLASS 429 257	SUBCLASS 446	ART. UNIT 4775 2815	EXAMINER Stem
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APPLICANTS

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TABLE

Structure and method for fabricating semiconductor structures and devices utilizing the formation of a compliant substrate comprising an oxygen-doped compound semiconductor layer

PTO-2040
12/89[illegible]

 TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
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